SEMICONDUCTOR

SC2065F

Silicon Carbide Schottky Diode
Reverse Voltage - 650 Volts
Forward Current - 20Amperes

Features

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V_F
- Temperature-independent Switching
- 175°C Operating Junction Temperature

ITO-220AC

SC2065F

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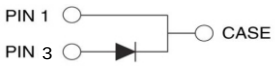


Benefits

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	650	V	T_C = 25˚C	
V_{RSM}	Surge Peak Reverse Voltage	650	V	T_C = 25˚C	
V_R	DC Blocking Voltage	650	V	T_C = 25˚C	
I_F	Forward Current	25 20	A	T_C ≤ 135˚C T_C ≤ 150˚C	
I_{FSM}	Non-Repetitive Forward Surge Current	170	A	T_C = 25˚C, t_p = 8.3ms, Half Sine Wave	
P_{tot}	Power Dissipation	50	W	T_C = 25˚C	Fig.3
T_C	Maximum Case Temperature	150	˚C		
T_J, T_{STG}	Operating Junction and Storage Temperature	-55 to 175	˚C		
	TO-247 Mounting Torque	1	Nm	M3 Screw	

Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.4 1.7	1.65 2.3	V	I_F = 20A, T_J = 25˚C I_F = 20A, T_J = 175˚C	Fig.1
I_R	Reverse Current	2 10	20 200	μA	V_R = 650V, T_J = 25˚C V_R = 650V, T_J = 175˚C	Fig.2
C	Total Capacitance	1190 115 96	/	pF	V_R = 0V, T_J = 25˚C, f = 1MHz V_R = 200V, T_J = 25˚C, f = 1MHz V_R = 400V, T_J = 25˚C, f = 1MHz	Fig.5
Q_C	Total Capacitive Charge	40	/	nC	V_R = 650V, I_F = 20A di/dt = 200A/μs, T_J = 25˚C	Fig.4

Thermal Characteristics

Symbol	Parameter	Typ.	Unit	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	3.0	˚C/W	Fig.6

Typical Performance

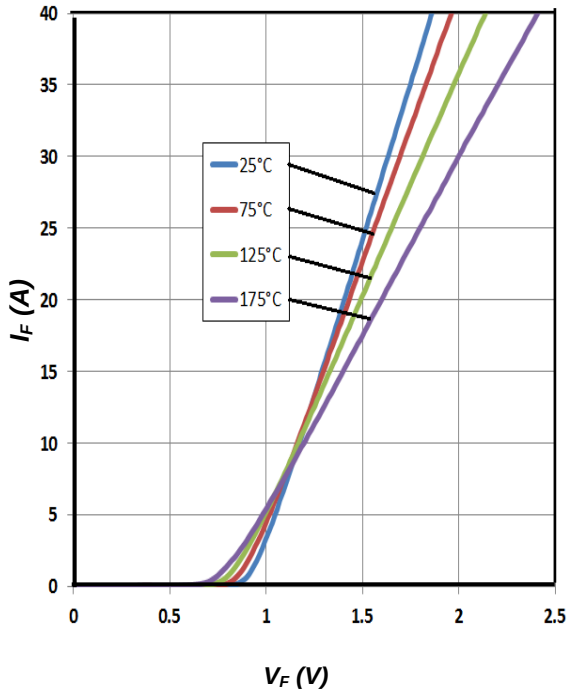


Figure 1. Forward Characteristics

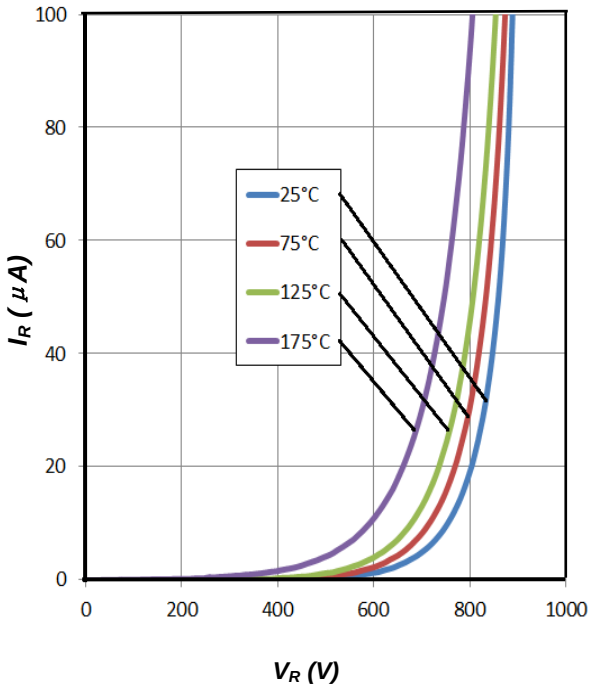


Figure 2. Reverse Characteristics

Typical Performance

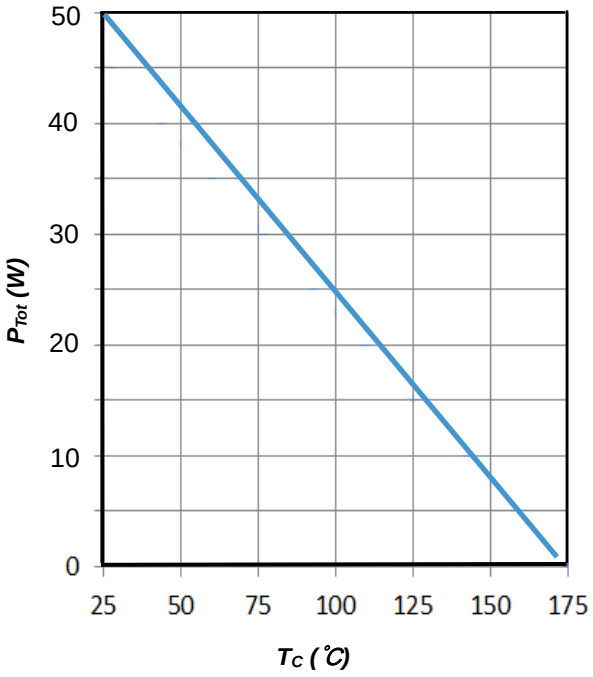


Figure 3. Power Derating

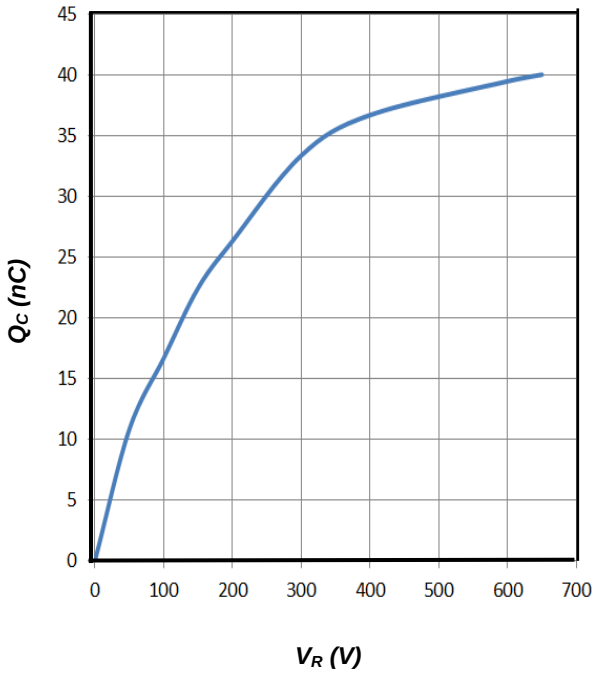


Figure 4. Total Capacitive Charge vs. Reverse Voltage

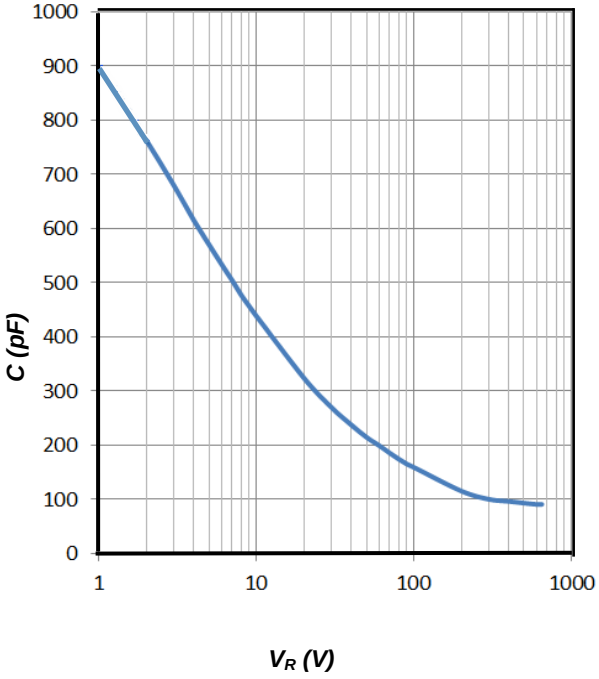


Figure 5. Total Capacitance vs. Reverse Voltage

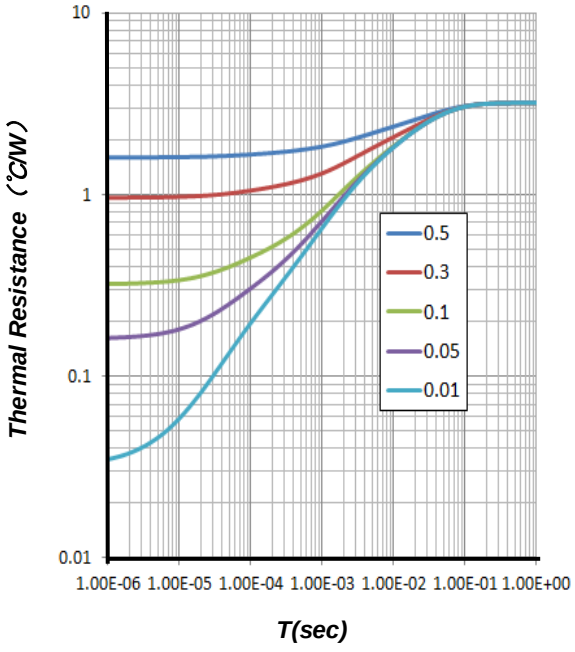
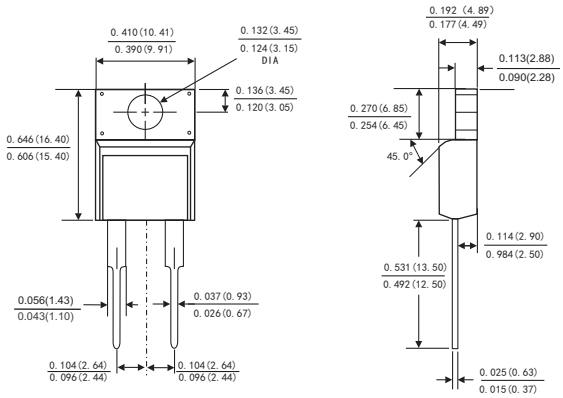


Figure 6. Transient Thermal Impedance

Package Dimensions

Package ITO-220AC

ITO-220AC



Dimensions in inches and (millimeters)

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